

MT3S37FS

VCO OSCILLETOR STAGE

UHF LOW NOISE AMPLIFIER APPLICATION

FEATURES

- Low Noise Figure :NF=1.2dB (@f=2GHz)
- High Gain:|S21e|^2=12.0dB (@f=2GHz)

Marking

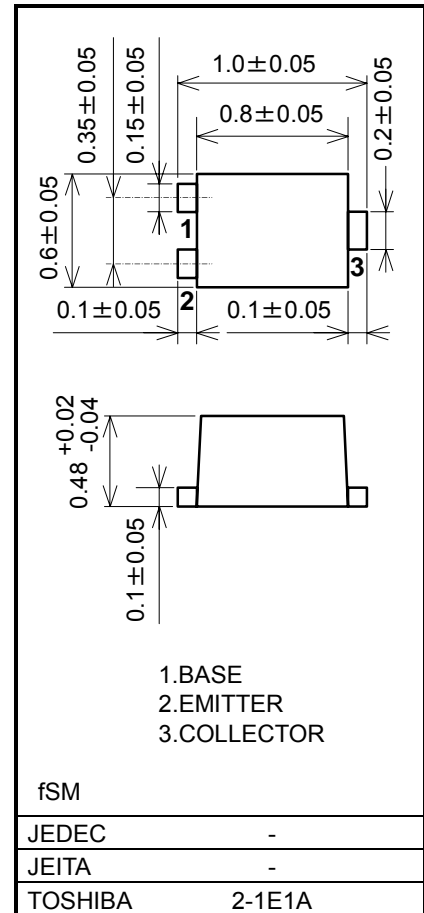


Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-Base voltage	V _{CBO}	8	V
Collector-Emitter voltage	V _{CEO}	4.5	V
Emitter-Base voltage	V _{EBO}	1.5	V
Collector-Current	I _C	50	mA
Base-Current	I _B	25	mA
Collector Power dissipation	P _C (Note)	100	mW
Junction temperature	T _j	150	°C
Storage temperature Range	T _{stg}	-55~150	°C

Note: Device mounted on a glass-epoxy PCB(0.88 cm² × 0.7 mm (t))

Unit:mm



Weight: 0.0006 g

Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Transition Frequency	fT	V _{CE} =3V, I _C =20mA, f=2GHz	15	19	-	GHz
Insertion Gain	S _{21e} ² (1)	V _{CE} =3V, I _C =20mA, f=1GHz	15	17	-	dB
	S _{21e} ² (2)	V _{CE} =3V, I _C =20mA, f=2GHz	10	12	-	dB
Noise Figure	NF(1)	V _{CE} =3V, I _C =3mA, f=1GHz	-	0.9	-	dB
	NF(2)	V _{CE} =3V, I _C =3mA, f=2GHz	-	1.2	1.8	dB

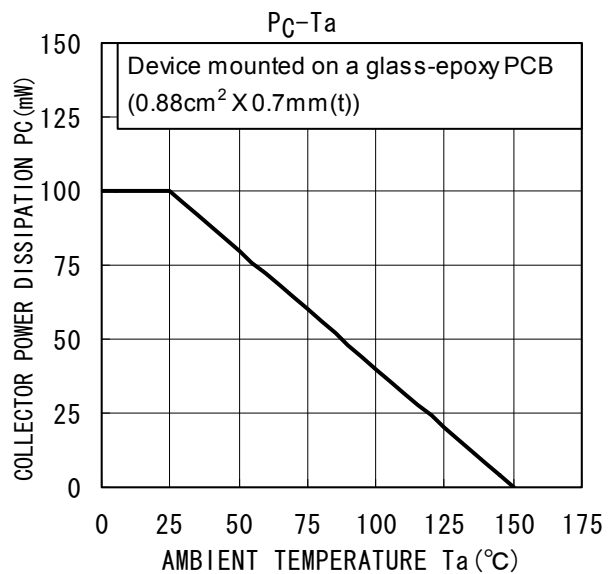
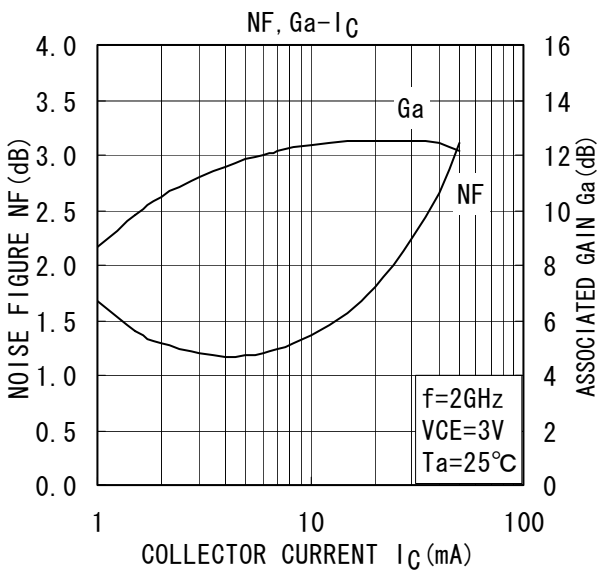
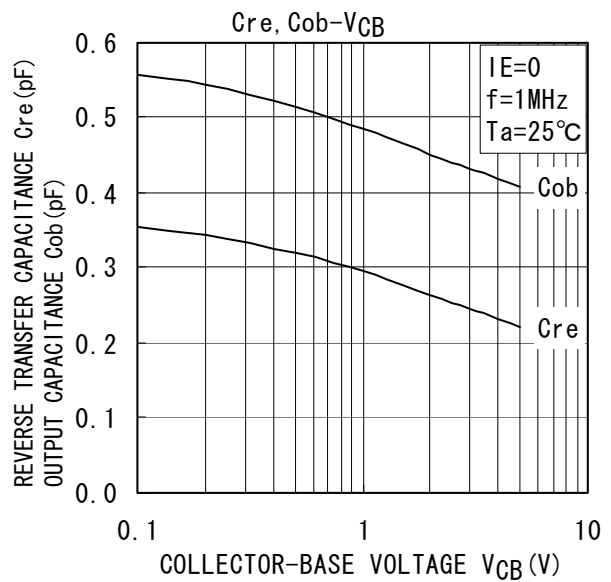
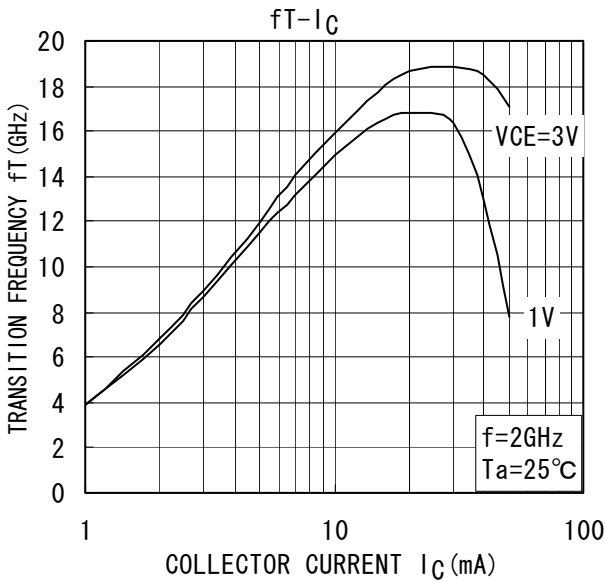
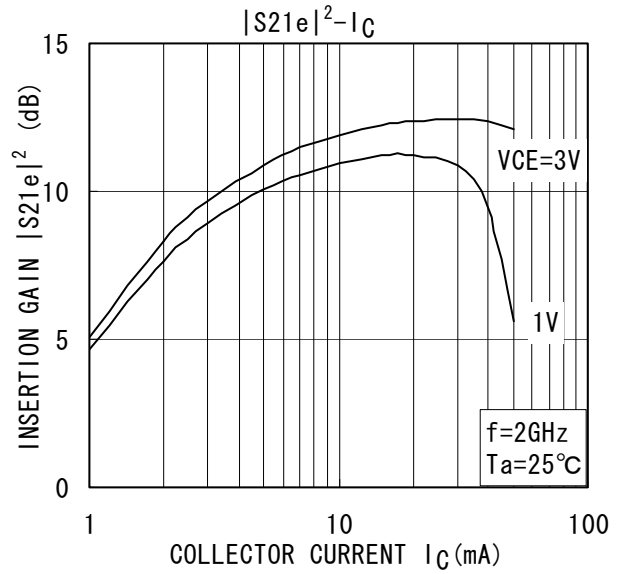
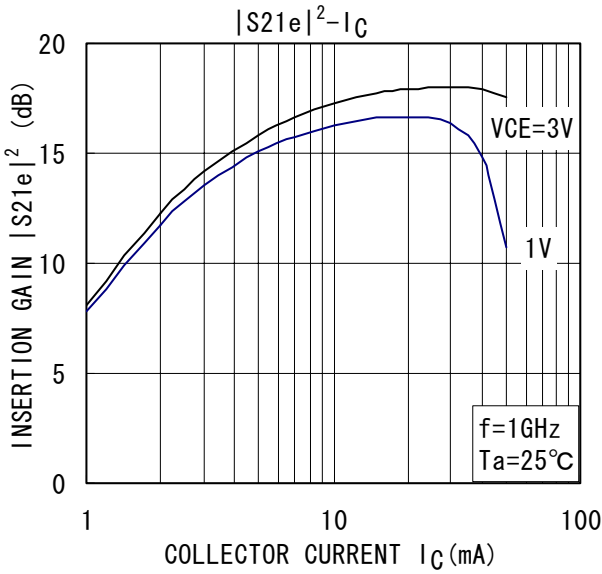
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector Cut-off Current	I _{CBO}	V _{CB} =8V, I _E =0	-	-	1	μA
Emitter Cut-off Current	I _{EBO}	V _{EB} =1V, I _C =0	-	-	1	μA
DC Current Gain	hFE	V _{CE} =3V, I _C =20mA	70	-	140	-
Output Capacitance	C _{ob}	V _{CB} =1V, I _E =0, f=1MHz	-	0.49	0.75	pF
Reverse Transistor Capacitance	C _{re}	V _{CB} =1V, I _E =0, f=1MHz (Note 1)	-	0.30	0.55	pF

Note 1: C_{re} is measured by 3 terminal method with capacitance bridge.

Caution: This device is sensitive to electrostatic discharge.

Please make enough tool and equipment earthed when you handle.



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